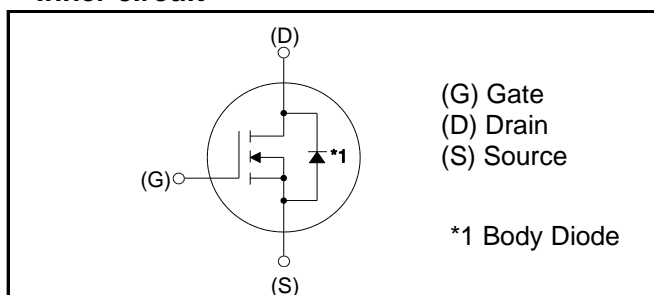


V_{DSS}	1200V
$R_{DS(on)}$ (Typ.)	450m Ω
I_D	10A ^{*1}

●Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive

●Inner circuit



●Application

- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	1200	V
Continuous drain current	I_D ^{*1}	10	A
Pulsed drain current	$I_{D,pulse}$ ^{*2}	25	A
Gate - Source voltage	V_{GSS}	-6 to 22	V
Junction temperature	T_j	175	°C
Range of storage temperature	T_{stg}	-55 to +175	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 1mA	1200	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} = 1200V, V _{GS} = 0V	-	1	10	μA
		T _j = 25°C	-	2	-	
Gate - Source leakage current	I _{GSS+}	V _{GS} = +22V, V _{DS} = 0V	-	-	100	nA
Gate - Source leakage current	I _{GSS-}	V _{GS} = -6V, V _{DS} = 0V	-	-	-100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 0.9mA	1.6	-	4.0	V
Static drain - source on - state resistance	R _{DS(on)} ^{*3}	V _{GS} = 18V, I _D = 3A	-	450	556	mΩ
		T _j = 25°C	-	610	-	
Gate input resistance	R _G	f = 1MHz, open drain	-	25	-	Ω

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Transconductance	g_{fs}^{*3}	V _{DS} = 10V, I _D = 3A	-	1.0	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	463	-	pF
Output capacitance	C _{oss}	V _{DS} = 800V	-	21	-	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	4	-	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V V _{DS} = 0V to 500V	-	31	-	pF
Turn - on delay time	$t_{d(on)}^{*3}$	V _{DD} = 400V, V _{GS} = 18V	-	19	-	ns
Rise time	t_r^{*3}	I _D = 3A	-	17	-	
Turn - off delay time	$t_{d(off)}^{*3}$	R _L = 133Ω	-	38	-	
Fall time	t_f^{*3}	R _G = 0Ω	-	34	-	
Turn - on switching loss	E _{on} ^{*3}	V _{DD} = 600V, I _D =3A V _{GS} = 18V/0V	-	47	-	μJ
Turn - off switching loss	E _{off} ^{*3}	R _G = 0Ω, L=500μH *E _{on} includes diode reverse recovery	-	17	-	

●Gate Charge characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q _g ^{*3}	V _{DD} = 400V	-	27	-	nC
Gate - Source charge	Q _{gs} ^{*3}	I _D = 3A	-	7	-	
Gate - Drain charge	Q _{gd} ^{*3}	V _{GS} = 18V	-	9	-	
Gate plateau voltage	V _(plateau)	V _{DD} = 400V, I _D = 3A	-	10.5	-	V

*1 For T_j=175°C and thermal dissipation to ambience of 85W or more.
Limited only by maximum temperature allowed.

*2 PW ≤ 10μs, Duty cycle ≤ 1%

*3 Pulsed

●Body diode electrical characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Inverse diode continuous, forward current	I_S^{*1}	$T_c = 25^\circ\text{C}$	-	-	10	A
Inverse diode direct current, pulsed	I_{SM}^{*2}		-	-	25	A
Forward voltage	V_{SD}^{*3}	$V_{GS} = 0\text{V}, I_S = 3\text{A}$	-	4.3	-	V
Reverse recovery time	t_{rr}^{*3}	$I_F = 3\text{A}, V_R = 400\text{V}$ $di/dt = 110\text{A}/\mu\text{s}$	-	19	-	ns
Reverse recovery charge	Q_{rr}^{*3}		-	13	-	nC
Peak reverse recovery current	I_{rrm}^{*3}		-	1.4	-	A

●Electrical characteristic curves

Fig.1 Typical Output Characteristics(I)

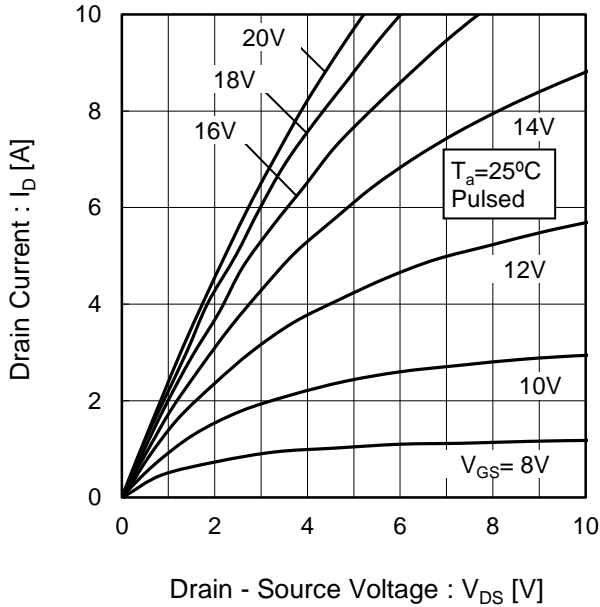


Fig.2 Typical Output Characteristics(II)

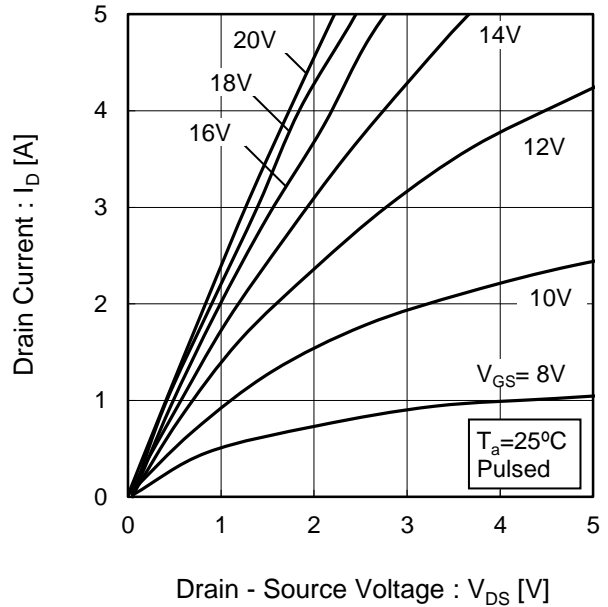


Fig.3 $T_j = 150^\circ\text{C}$ Typical Output Characteristics(I)

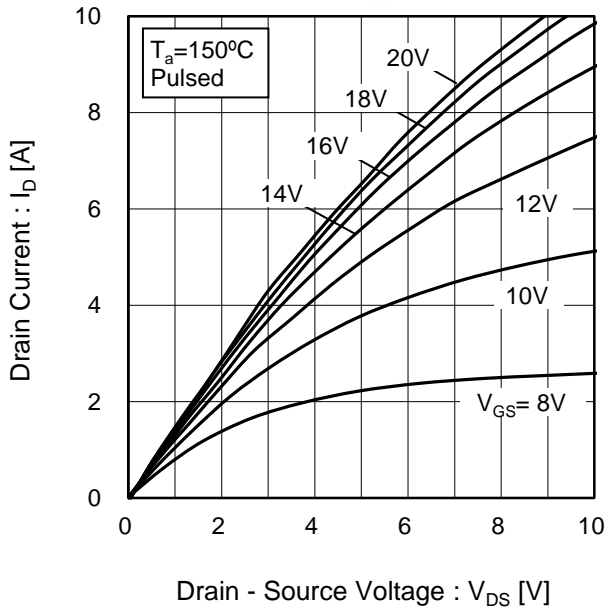
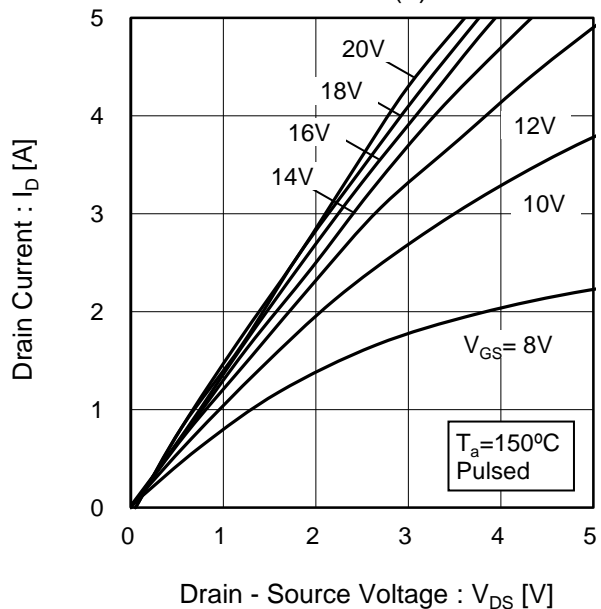


Fig.4 $T_j = 150^\circ\text{C}$ Typical Output Characteristics(II)



●Electrical characteristic curves

Fig.5 Typical Transfer Characteristics (I)

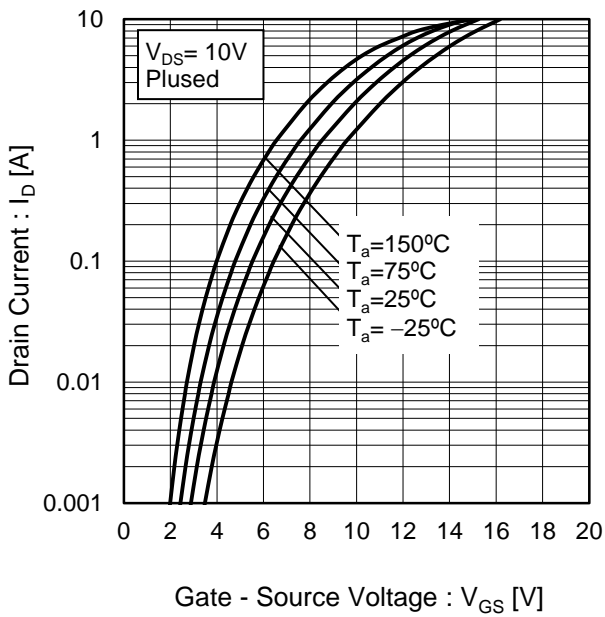


Fig.6 Typical Transfer Characteristics (II)

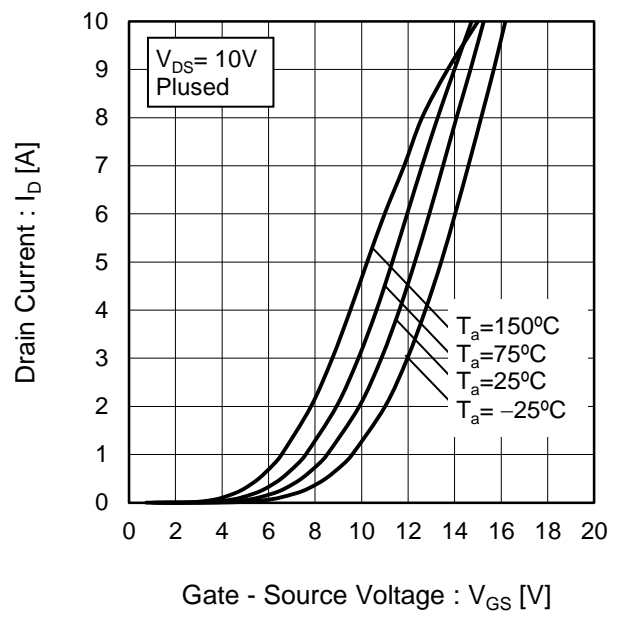


Fig.7 Gate Threshold Voltage vs. Junction Temperature

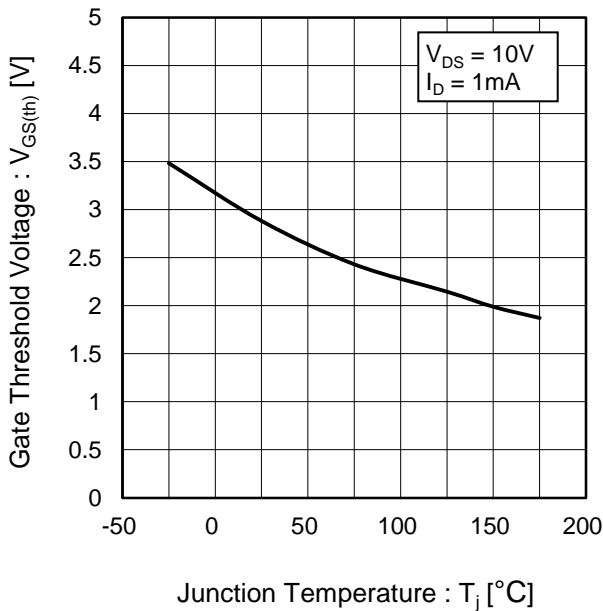
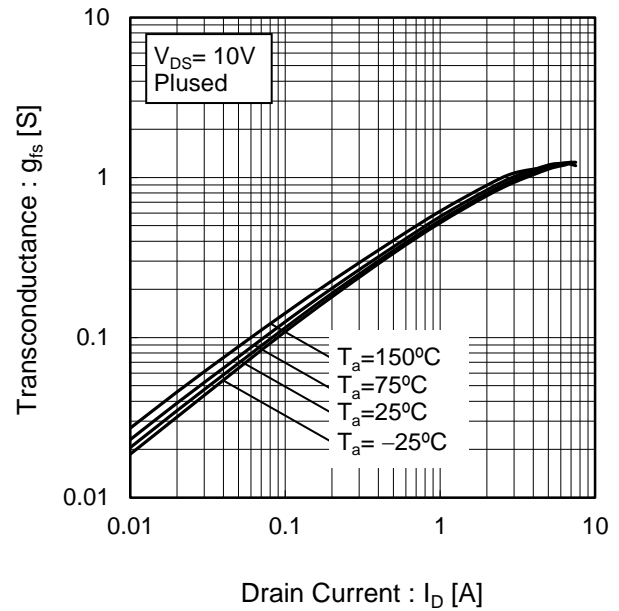


Fig.8 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.9 Static Drain - Source On - State Resistance vs. Gate Source Voltage

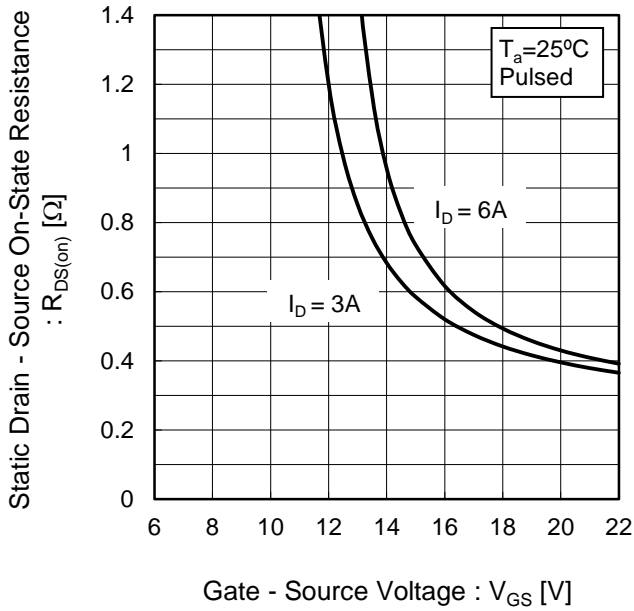


Fig.10 Static Drain - Source On - State Resistance vs. Junction Temperature

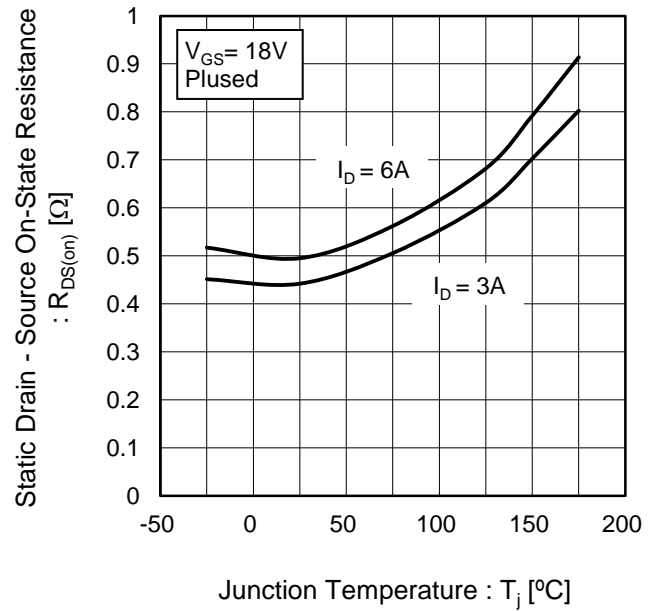
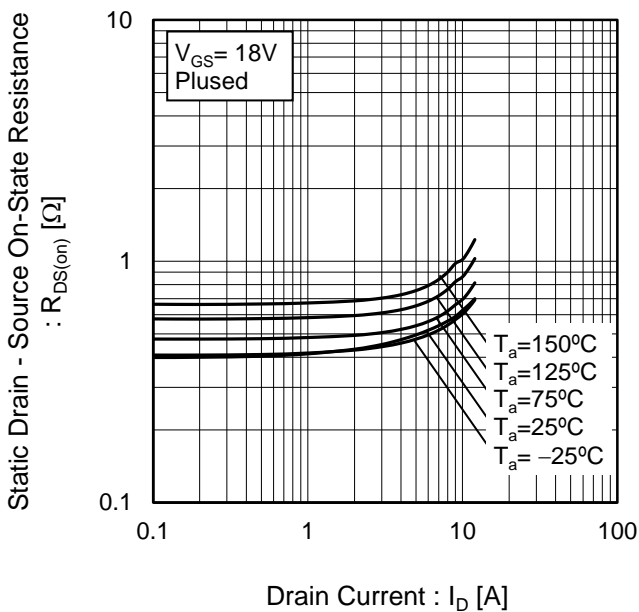


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current



●Electrical characteristic curves

Fig.12 Typical Capacitance vs. Drain - Source Voltage

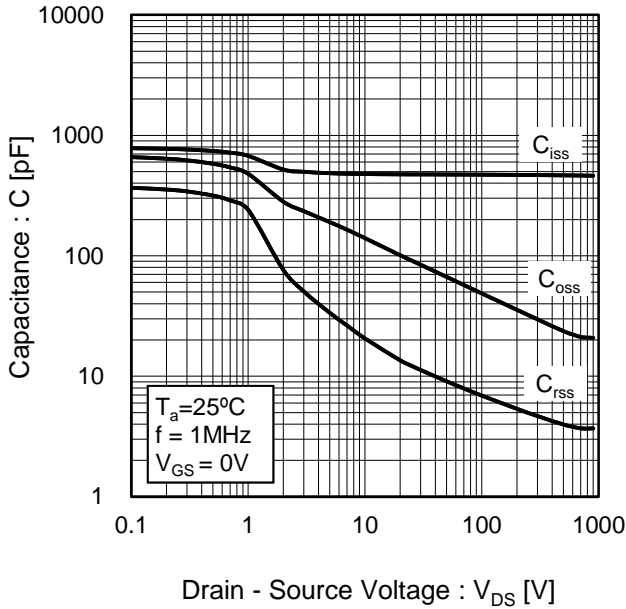


Fig.13 Coss Stored Energy

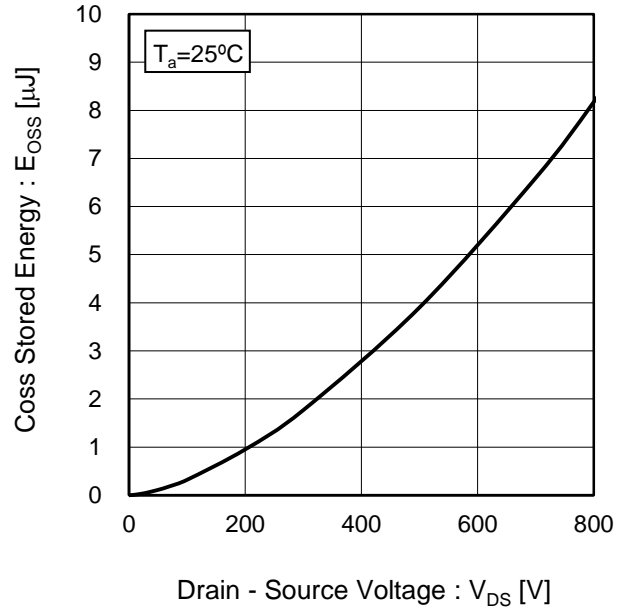


Fig.14 Switching Characteristics

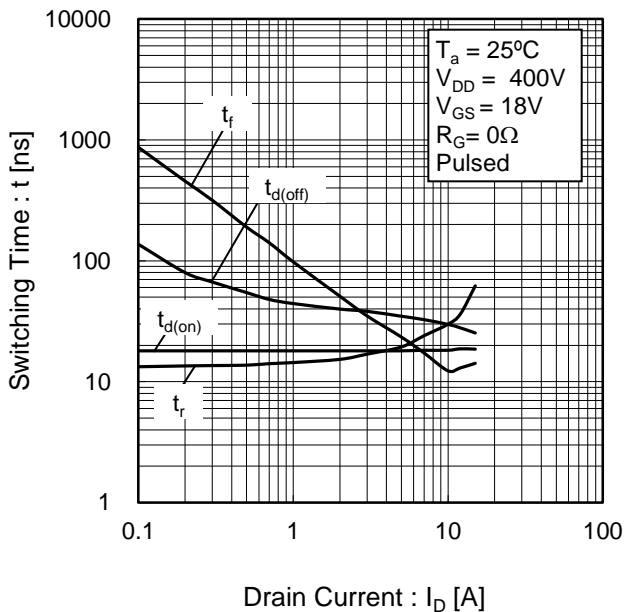
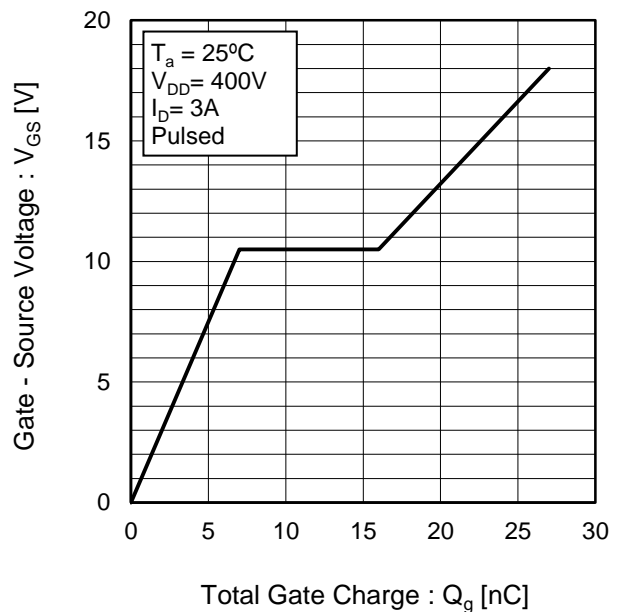


Fig.15 Dynamic Input Characteristics



●Electrical characteristic curves

Fig.16 Typical Switching Loss vs. Drain - Source Voltage

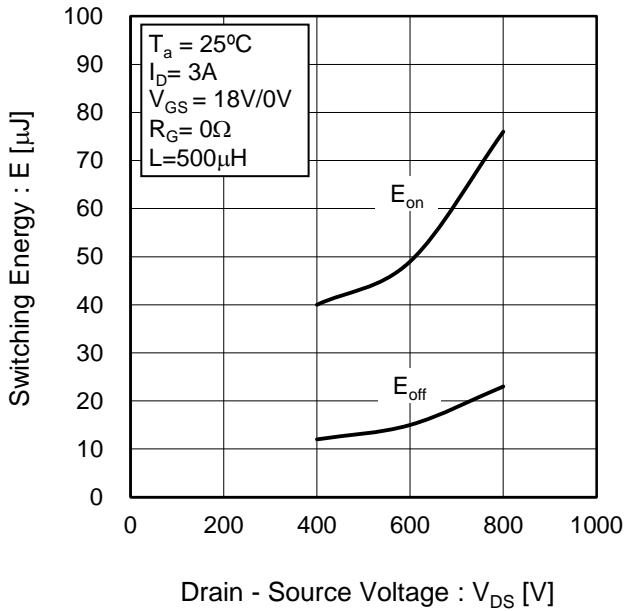


Fig.17 Typical Switching Loss vs. Drain Current

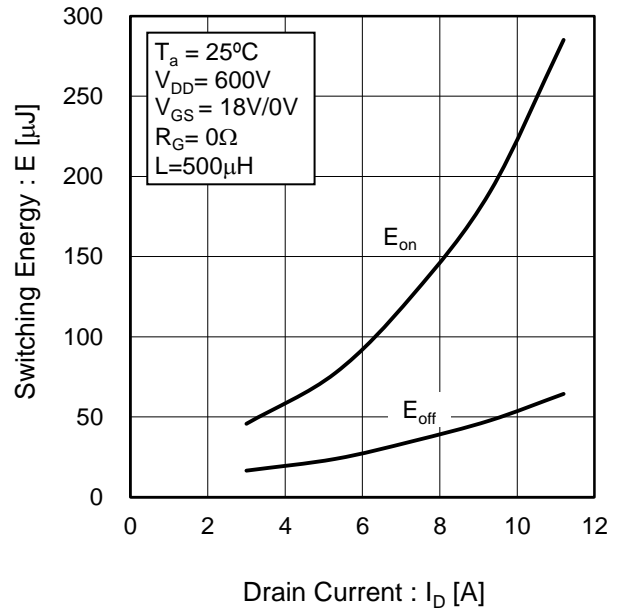
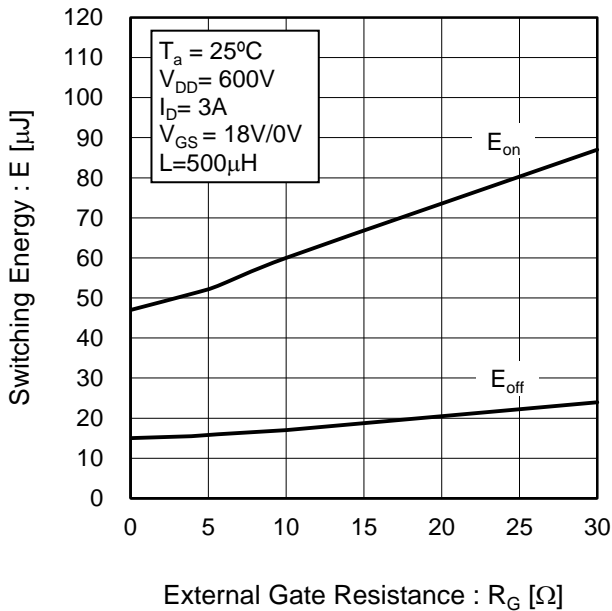


Fig.18 Typical Switching Loss vs. External Gate Resistance



●Electrical characteristic curves

Fig.19 Inverse Diode Forward Current vs. Source - Drain Voltage

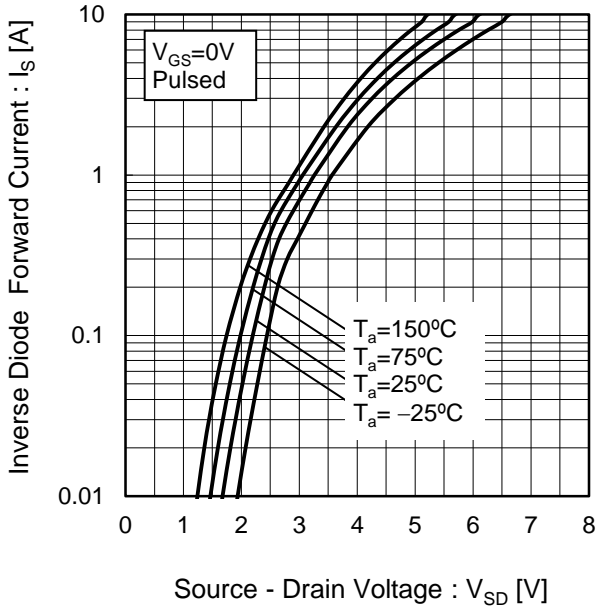
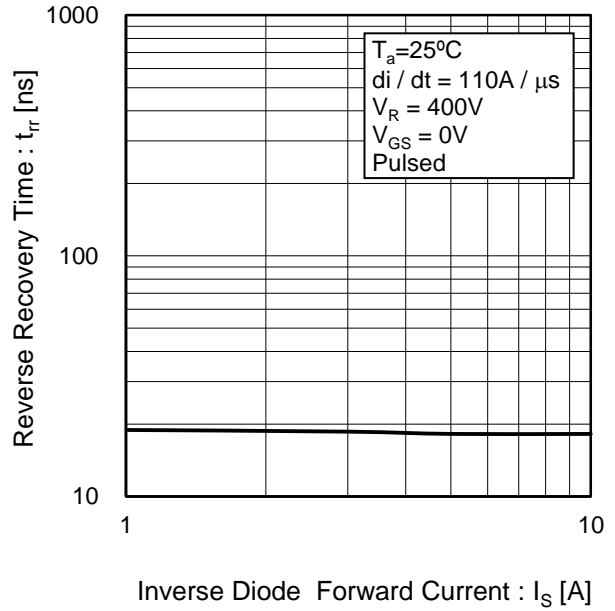


Fig.20 Reverse Recovery Time vs. Inverse Diode Forward Current



● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

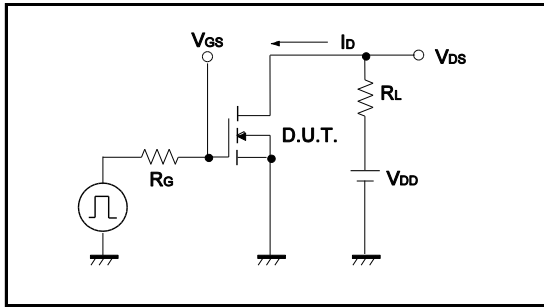


Fig.1-2 Switching Waveforms

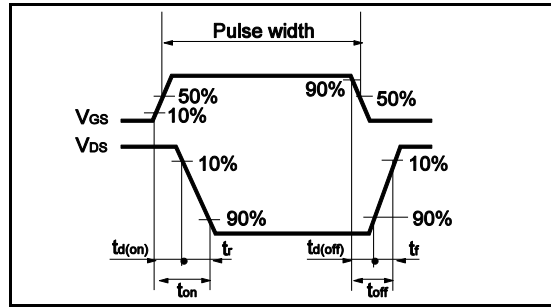


Fig.2-1 Gate Charge Measurement Circuit

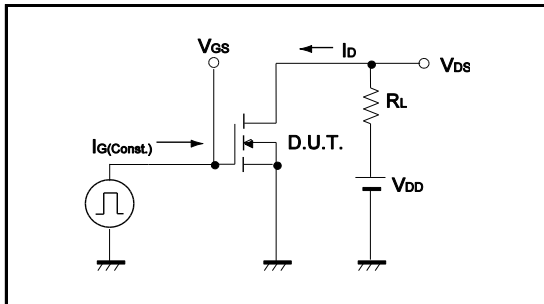


Fig.2-2 Gate Charge Waveform

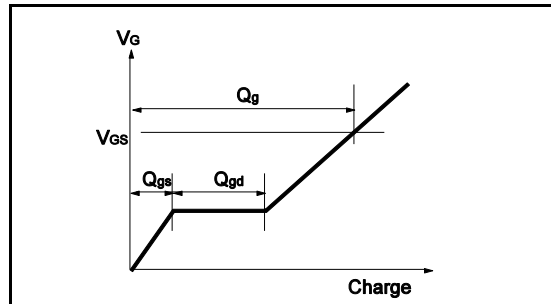


Fig.3-1 Switching Energy Measurement Circuit

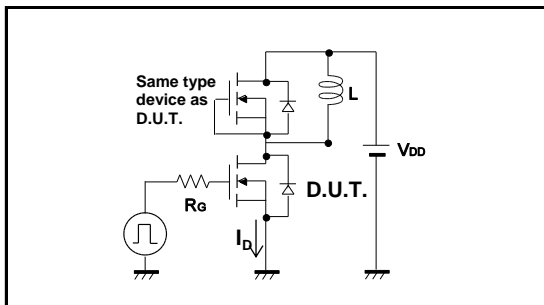


Fig.3-2 Switching Waveforms

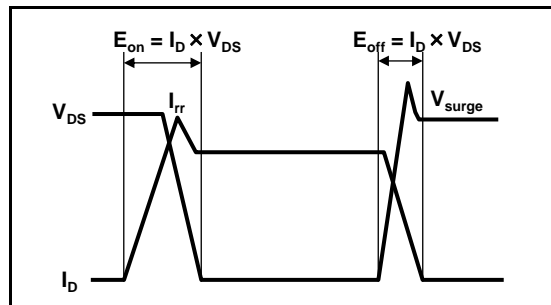


Fig.4-1 Reverse Recovery Time Measurement Circuit

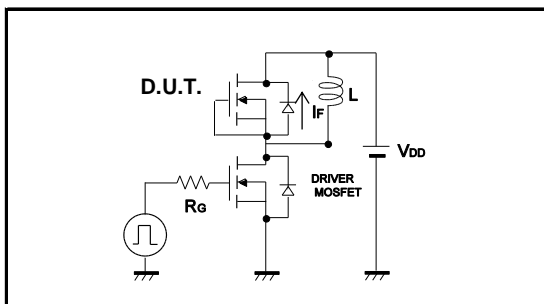
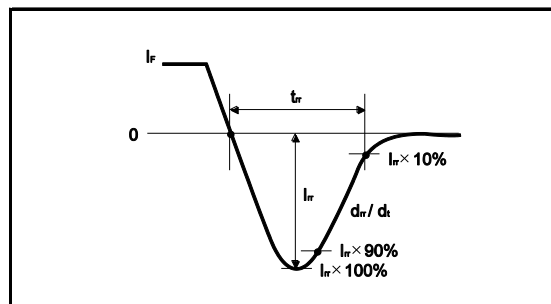


Fig.4-2 Reverse Recovery Waveform



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